# **ON Semiconductor**

# Is Now



To learn more about onsemi™, please visit our website at www.onsemi.com

onsemi and ONSEMI. and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/ or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi products for any such unintended or unauthorized application,

# Very Low Forward Voltage Trench-based Schottky Rectifier

Exceptionally Low  $V_F = 0.50 \text{ V}$  at  $I_F = 5 \text{ A}$ 

## **Features**

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

# **Typical Applications**

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

# **Mechanical Characteristics**

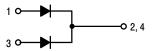
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec



# ON Semiconductor®

www.onsemi.com

# PIN CONNECTIONS





## **MARKING DIAGRAMS**



A = Assembly Location

Y = Year WW = Work Week

AKA = Polarity Designator

G = Pb-Free Package/Halide Package

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

#### **MAXIMUM RATINGS**

| Rating   |                         | Symbol   | Value       | Unit |
|--|-------------------------|--|-------------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                     |                         | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | 80          | V    |
| Average Rectified Forward Current (Rated V <sub>R</sub> , T <sub>C</sub> = 130°C)                          | Per device<br>Per diode | I <sub>F(AV)</sub>                                     | 20<br>10    | А    |
| Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz, T <sub>C</sub> = 125°C)       | Per device<br>Per diode | I <sub>FRM</sub>                                       | 40<br>20    | А    |
| Nonrepetitive Peak Surge Current<br>(Surge applied at rated load conditions halfwave, single phase, 60 Hz) |                         | I <sub>FSM</sub>                                       | 100         | А    |
| Operating Junction Temperature   |                         | TJ   | -40 to +150 | °C   |
| Storage Temperature  |                         | T <sub>stg</sub>                                       | -40 to +150 | °C   |
| Voltage Rate of Change (Rated V <sub>R</sub> )   |                         | dv/dt  | 10,000      | V/μs |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# THERMAL CHARACTERISTICS

| Rating                     |   | Symbol                        | Value     | Unit |
|----------------------------|---|-------------------------------|-----------|------|
| Maximum Thermal Resistance | Junction-to-Case<br>Junction-to-Ambient | $R_{	heta JC} \ R_{	heta JA}$ | 2.0<br>70 | °C/W |

## **ELECTRICAL CHARACTERISTICS** (Per Leg unless otherwise noted)

| Rating  | Symbol         | Тур          | Max       | Unit        |
|---|----------------|--------------|-----------|-------------|
| Maximum Instantaneous Forward Voltage (Note 1) $ (I_F = 5 \text{ A}, T_J = 25^{\circ}\text{C}) $ $ (I_F = 10 \text{ A}, T_J = 25^{\circ}\text{C}) $ | V <sub>F</sub> | 0.55<br>0.65 | -<br>0.98 | <b>&gt;</b> |
| (I <sub>F</sub> = 5 A, T <sub>J</sub> = 125°C)<br>(I <sub>F</sub> = 10 A, T <sub>J</sub> = 125°C)   |                | 0.50<br>0.58 | -<br>0.82 |             |
| Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, T <sub>J</sub> = 25°C) (Rated dc Voltage, T <sub>J</sub> = 125°C)                 | I <sub>R</sub> | 20<br>10     | 600<br>20 | μA<br>mA    |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2.0%

#### **ORDERING INFORMATION**

| Device      | Package                           | Shipping        |
|-------------|-----------------------------------|-----------------|
| NTSV2080CTG | TO-220AB<br>(Pb-Free/Halide Free) | 50 Units / Rail |

## **TYPICAL CHARACTERISITICS**

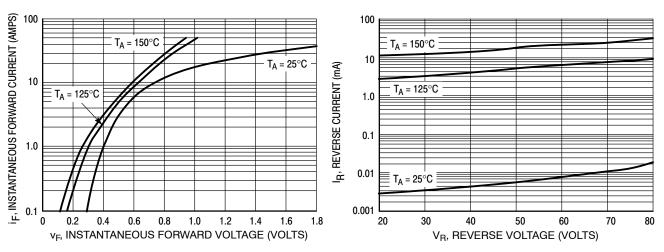
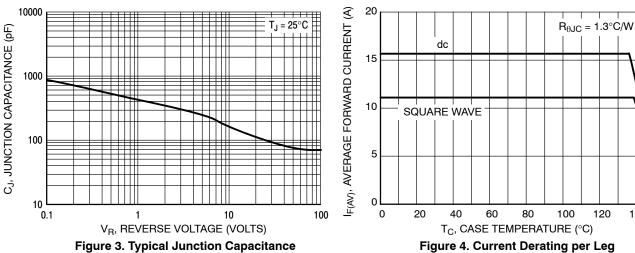


Figure 1. Typical Forward Voltage

**Figure 2. Typical Reverse Current** 

120

140

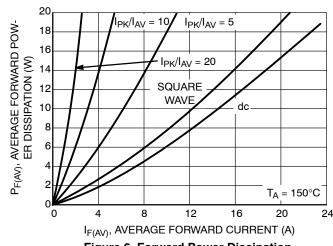


 $R_{\theta JC} = 1.3^{\circ}C/W$ 

120

140

Figure 3. Typical Junction Capacitance



T<sub>C</sub>, CASE TEMPERATURE (°C) Figure 5. Current Derating

Figure 6. Forward Power Dissipation

40

35

30

25

20

15 10

0

dc

**SQUARE WAVE** 

20

I<sub>F(AV)</sub>, AVERAGE FORWARD CURRENT (A)

# **TYPICAL CHARACTERISITICS**

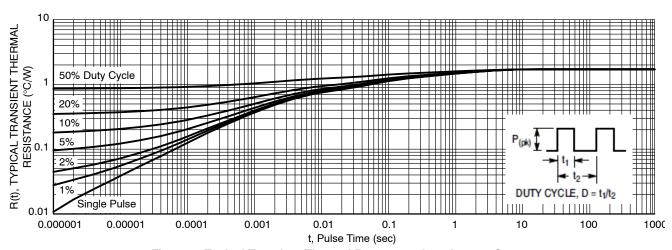
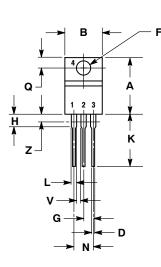
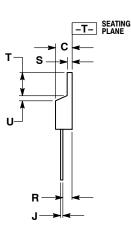


Figure 7. Typical Transient Thermal Response, Junction-to-Case

#### PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AH** 





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
  DIMENSION Z DEFINES A ZONE WHERE ALL
  BODY AND LEAD IRREGULARITIES ARE ALLOWED

|     | INCHES |       | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN    | MAX   | MIN    | MAX    |
| Α   | 0.570  | 0.620 | 14.48  | 15.75  |
| В   | 0.380  | 0.415 | 9.66   | 10.53  |
| С   | 0.160  | 0.190 | 4.07   | 4.83   |
| D   | 0.025  | 0.038 | 0.64   | 0.96   |
| F   | 0.142  | 0.161 | 3.61   | 4.09   |
| G   | 0.095  | 0.105 | 2.42   | 2.66   |
| Н   | 0.110  | 0.161 | 2.80   | 4.10   |
| J   | 0.014  | 0.024 | 0.36   | 0.61   |
| K   | 0.500  | 0.562 | 12.70  | 14.27  |
| L   | 0.045  | 0.060 | 1.15   | 1.52   |
| N   | 0.190  | 0.210 | 4.83   | 5.33   |
| Q   | 0.100  | 0.120 | 2.54   | 3.04   |
| R   | 0.080  | 0.110 | 2.04   | 2.79   |
| S   | 0.045  | 0.055 | 1.15   | 1.39   |
| T   | 0.235  | 0.255 | 5.97   | 6.47   |
| U   | 0.000  | 0.050 | 0.00   | 1.27   |
| ٧   | 0.045  |       | 1.15   |        |
| Z   |        | 0.080 |        | 2.04   |

STYLE 6:

ANODE 2. CATHODE

- ANODE 3.
- CATHODE

ON Semiconductor and the an are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

# **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada

Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative